

Hsinchu Science Park, Hsinchu 300, Taiwan TEL: +886-3-5643931 FAX: +886-3-5644624



**Product: SMD1812P110TF/24** 

Revision: H

Date: October 06, 2011

Page: 1 of 1

## **Device Specification**

## **ELECTRICAL CHARACTERISTICS**



Part Number				ć		Maximum Time To Trip		Resistance	
Fait Nulliber	I <sub>hold</sub> (A)	I <sub>trip</sub> (A)	V <sub>max</sub> (Vdc)	I <sub>max</sub> (A)	P <sub>d typ</sub> (W)	Current (A)	Time (Sec.)	$R_{min} \ (\Omega)$	$R_{1max}$ $(\Omega)$
SMD1812P110TF/24	1.10	1.95	24	20	0.80	8.00	0.50	0.060	0.200

Note: Ihold = Hold current: maximum current device will pass without tripping in 23°C still air.

 $I_{trip}$  = Trip current: minimum current at which the device will trip in 23 °C still air.

V<sub>max</sub> = Maximum voltage device can withstand without damage at rated current (I<sub>max</sub>)

I<sub>max</sub> = Maximum fault current device can withstand without damage at rated voltage (V<sub>max</sub>)

P<sub>d typ</sub> = Typical power dissipated from device when in the tripped state at 23 °C still air.

R<sub>min</sub> = Minimum resistance of device in initial (un-soldered) state.

R<sub>1max</sub> = Maximum resistance of device at 23°C measured one hour after tripping or reflow soldering of 260°C for 20 sec.

\*Value specified were determined using the PWB with 0.030"\*1.5oz copper traces.

\*Customer should verify the device performance in their specified conditions.

Caution: Operation beyond the specified rating may result in damage and possible arcing and flame.

Recognitions:



## 

Note: Polystar is Polytronics's manufacturing site in China. The Polystar ID marking shall appear on smallest package.

## **PHYSICAL DIMENSIONS (mm)**

Dout Number	A		В		С		D		E	
Part Number	Min.	Max.								
SMD1812P110TF/24	4.37	4.73	3.07	3.41	0.55	1.07	0.30	1.20	0.15	0.65

**Specifications** are subject to change without notice.